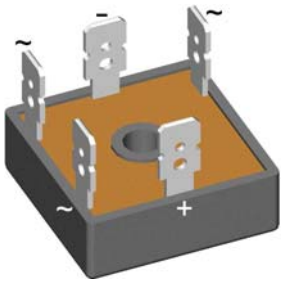
Standard Rectifier Module

3~ Rectifier		
V_{RRM}	=	1400 V
I_{DAV}	=	27 A
I_{FSM}	=	550 A

3~ Rectifier Bridge

Part number

VUO36-14NO8



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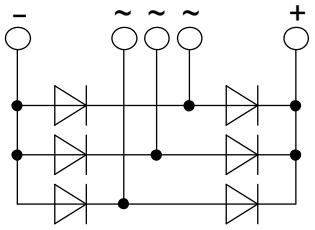


Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

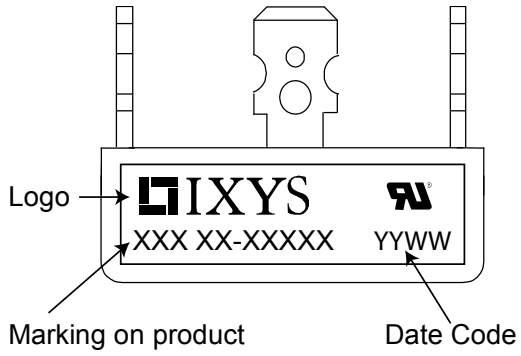
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: FO-B

- Industry standard outline
- RoHS compliant
- ¼“ fast-on terminals
- Easy to mount with one screw

Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			1500	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			1400	V
I_R	*reverse current*	V_R = 1400 V	T_{VJ} = 25°C			40	µA
		V_R = 1400 V	T_{VJ} = 150°C			1.5	mA
V_F	*forward voltage drop*	I_F = 15 A	T_{VJ} = 25°C			1.04	V
		I_F = 45 A				1.23	V
		I_F = 15 A	T_{VJ} = 125 °C			0.93	V
		I_F = 45 A				1.18	V
I_{DAV}	*bridge output current*	T_C = 85°C	T_{VJ} = 150°C			27	A
		rectangular d = ⅓					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			0.76	V
r_F	*slope resistance* }					9.1	mΩ
R_{thJC}	*thermal resistance junction to case*					7	K/W
R_{thCH}	*thermal resistance case to heatsink*				1		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			17	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			550	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			595	A
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			470	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			505	A
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			1.52	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.48	kA²s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			1.11	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.06	kA²s
C_J	*junction capacitance*	V_R = 400 V; f = 1 MHz	T_{VJ} = 25°C		18		pF

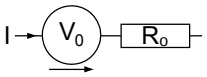
Package FO-B					Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I_{RMS}	*RMS current*	per terminal					100	A
T_{stg}	*storage temperature*				-40		125	°C
T_{VJ}	*virtual junction temperature*				-40		150	°C
Weight						20		g
M_D	*mounting torque*				1.8		2.2	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*		*terminal to terminal*	9.0	7.0			mm
$d_{Spb/Apb}$			*terminal to backside*	10.0	10.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA		3000			V
		t = 1 minute			2500			V



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO36-14NO8	VUO36-14NO8	Box	50	465151

Equivalent Circuits for Simulation

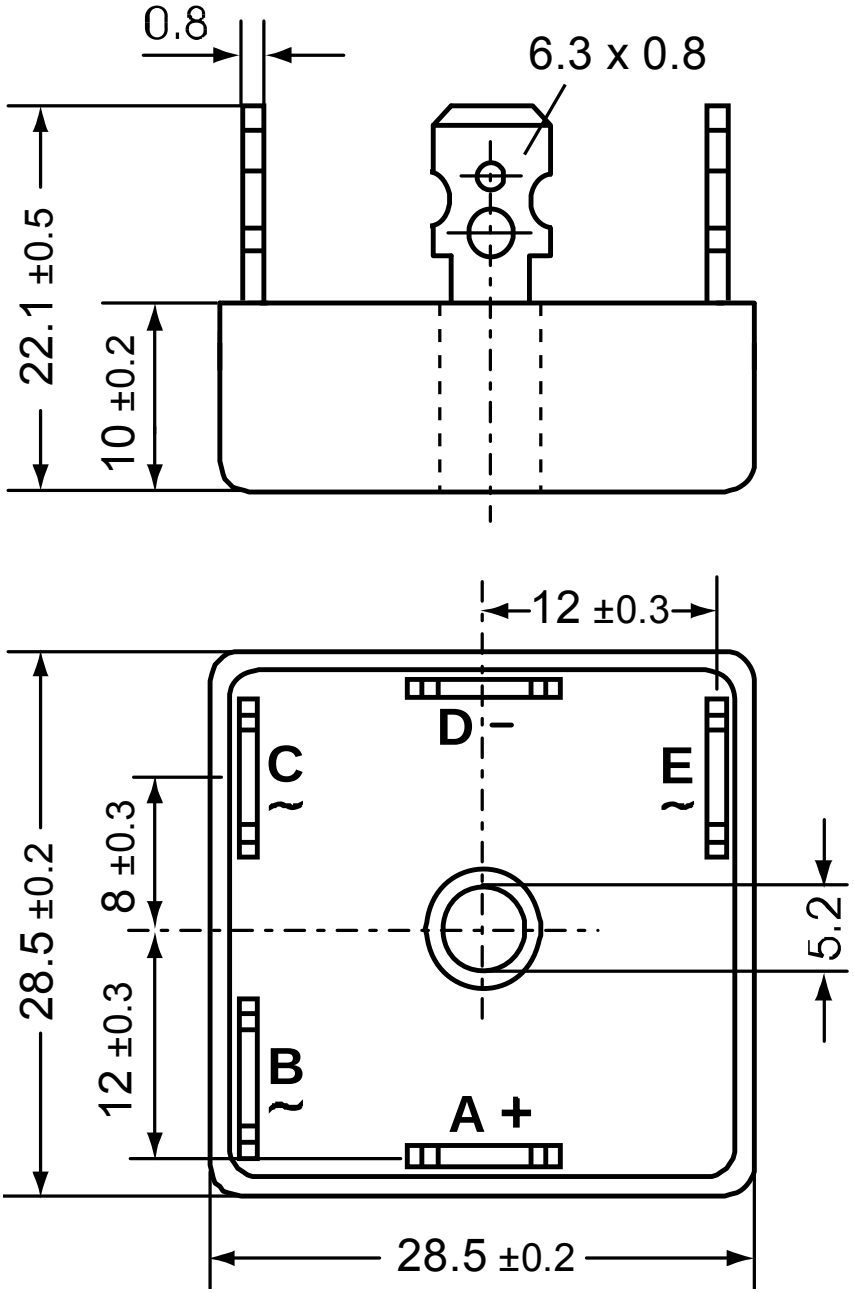
** on die level* T_{VJ} = 150 °C

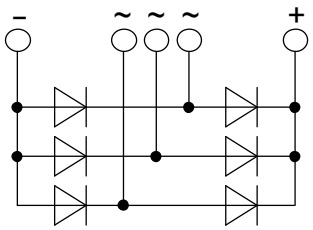


Rectifier

$V_{0\,max}$	*threshold voltage*	0.76	V
$R_{0\,max}$	*slope resistance **	7.9	mΩ

Outlines FO-B





Rectifier

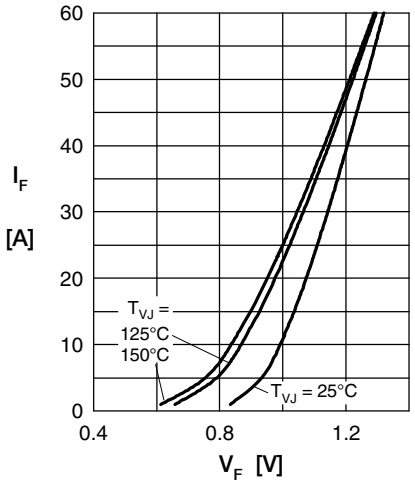


Fig. 1 Forward current vs. voltage drop per diode

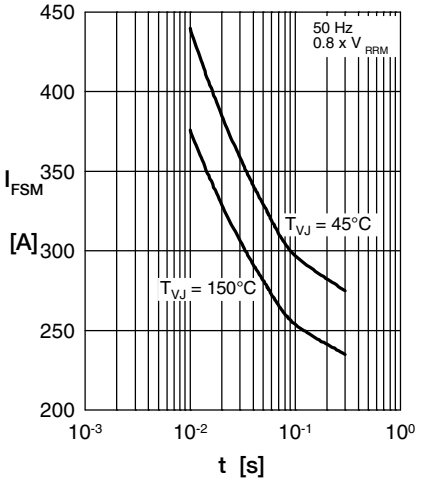


Fig. 2 Surge overload current vs. time per diode

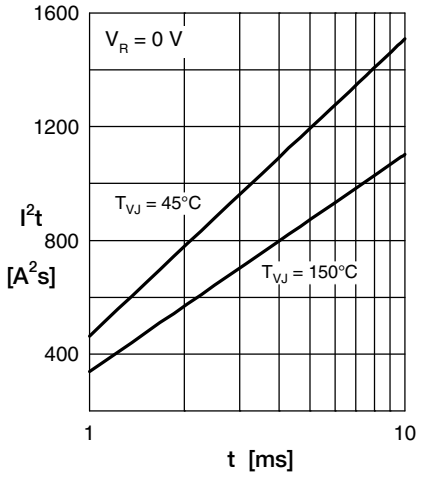


Fig. 3 I^2t vs. time per diode

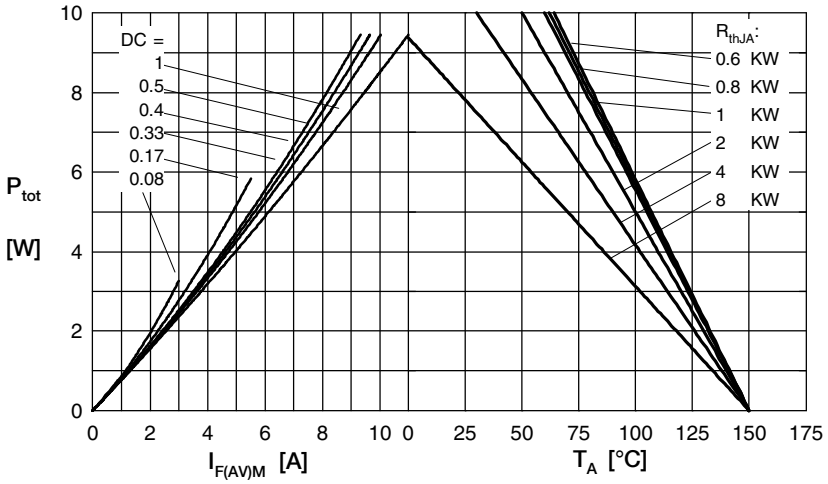


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

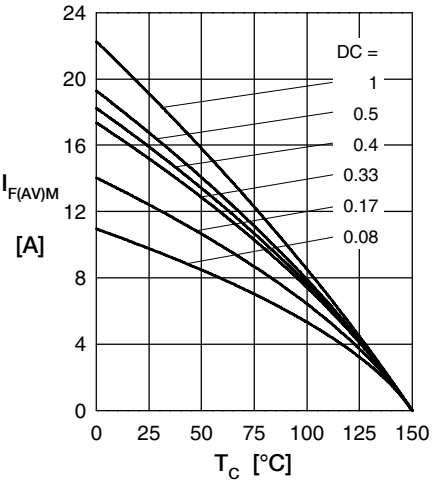


Fig. 5 Max. forward current vs. case temperature per diode

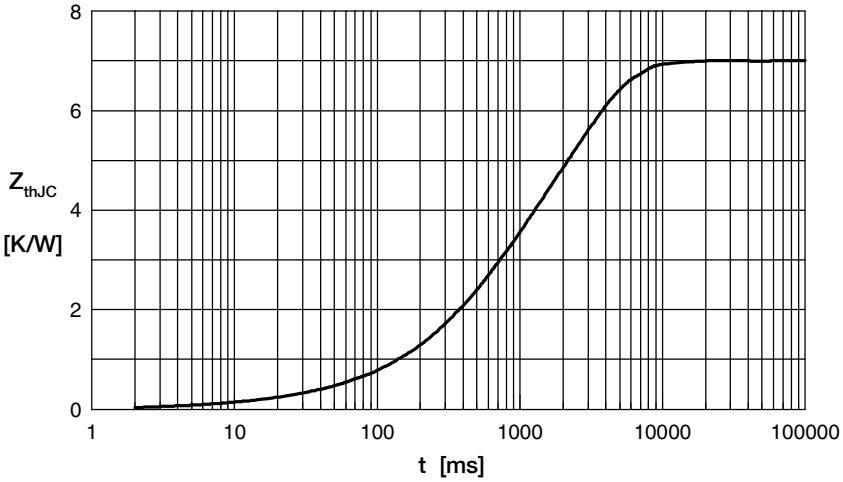


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.040	0.005
2	0.150	0.030
3	1.710	0.400
4	5.100	2.300

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